

# United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/786,348	02/24/2004	Scott J. DeBoer	1999-1335.01/US 4548		
7590 12/07/2004			EXAMINER		
Kevin D. Martin			PHAM, HOAI V		
Micron Technology, Inc.			<del></del>		
8000 S. Federal Way, MS 1-525 Boise, ID 83716			ART UNIT	PAPER NUMBER	
			2814		

DATE MAILED: 12/07/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

			XK/_		
		Application No.	Applicant(s)		
Office Action Summary		10/786,348	DEBOER ET AL.		
		Examiner	Art Unit		
		Hoai v Pham	2814		
- Period fo	<ul> <li>The MAILING DATE of this communication appropriate the property</li> </ul>	pears on the cover sheet with the c	orrespondence address		
THE N - Extensions - If the p - If NO - Failure Any re	DRTENED STATUTORY PERIOD FOR REPL MAILING DATE OF THIS COMMUNICATION. sions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a repl period for reply is specified above, the maximum statutory period e to reply within the set or extended period for reply will, by statute apply received by the Office later than three months after the mailin d patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be tin ly within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from e, cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).		
Status					
1)⊠	Responsive to communication(s) filed on 21 S	September 2004.			
·	•	s action is non-final.			
	Since this application is in condition for allowa		esecution as to the merits is		
· ·	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.				
Dispositio	on of Claims		•		
5)□ 6)⊠ 7)□	Claim(s) 1-6 and 15-22 is/are pending in the a 4a) Of the above claim(s) is/are withdra Claim(s) is/are allowed. Claim(s) 1-6 and 15-22 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/o	wn from consideration.			
Application	on Papers	•			
10)🛛 🗆	The specification is objected to by the Examine $\Gamma$ in the drawing(s) filed on $2/24/2004$ is/are: a) $\Gamma$ Applicant may not request that any objection to the Replacement drawing sheet(s) including the correction oath or declaration is objected to by the Example 2.	accepted or b) objected to by a drawing(s) be held in abeyance. Section is required if the drawing(s) is ob	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).		
Priority u	nder 35 U.S.C. § 119				
<ul> <li>12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents have been received.</li> <li>2. Certified copies of the priority documents have been received in Application No.</li> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>					
2) Notice	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) No(s)/Mail Date 2/24/04	4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal F 6) Other:			

### **DETAILED ACTION**

#### Election/Restrictions

Applicant's election without traverse of claims 1-6 in the reply filed on September
 21, 2004 is acknowledged.

### Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 1-5 and 15-20 are rejected under 35 U.S.C. 102(e) as being anticipated by Noble [U.S. Pat. 6,190,960].

The applied reference has a common assignee with the instant application. Based upon the earlier effective U.S. filing date of the reference, it constitutes prior art under 35 U.S.C. 102(e). This rejection under 35 U.S.C. 102(e) might be overcome either by a showing under 37 CFR 1.132 that any invention disclosed but not claimed in the reference was derived from the inventor of this application and is thus not the invention "by another," or by an appropriate showing under 37 CFR 1.131.

With respect to claim 1, Noble (fig. 17, cols. 6-10) discloses a semiconductor device comprising:

first and second contact pads (1530, 1531);

a first plug portion (1010) electrically coupled with the first contact pad (1530);

a capacitor bottom plate (1001) electrically coupled with the second contact pad (1531);

a dielectric etch stop liner (800) interposed between the bottom plate (1002) and the first plug portion (1010);

a capacitor top plate (1210) having a portion which at least partially extends over the etch stop liner, wherein the top plate portion is further from the first contact pad than a top surface of the first plug portion, and wherein the top plate has an opening therein; and

a second plug portion (1510) electrically coupled with the first plug portion (1010) and extending through the opening in the top plate.

With respect to claim 2, Noble (fig. 17, col. 10, lines 1-5) further discloses that a dielectric spacer which electrically separates the second plug portion (1510) from the capacitor top plate portion (1210).

With respect to claim 3, Noble (fig. 17) discloses that the bottom plate comprises, in cross section, at least two vertically-oriented portions which define a container, wherein at least part of each vertically-oriented portion of the bottom plate is interposed

between two vertically-oriented portions of the top plate and is separated by the two vertically-oriented portions of the top plate by a capacitor cell dielectric layer to form a double-sided container capacitor.

With respect to claim 4, Noble (fig. 17) further discloses that a capacitor cell dielectric layer (1200) which contacts the etch stop liner (800) and the capacitor top plate (1210).

With respect to claim 5, Noble (fig. 17) further discloses that a receptacle defined by said capacitor top plate (1210), wherein the receptacle is interposed between the first plug portion (1010) and the capacitor bottom plate (1001).

With respect to claim 15, Noble (fig. 17, cols. 6-10) discloses a semiconductor device comprising:

first and second conductive storage capacitor bottom plates (1001, 1002) each comprising a vertically-oriented sidewall;

a conductive plug (1010) interposed between the first and second conductive storage capacitor bottom plates (1001, 1002); and

a conductive storage capacitor top plate (1210) comprising an opening therein and further comprising first and second vertical surfaces which define a first receptacle and third and fourth vertical surfaces which define a second receptacle,

Page 5

wherein the first receptacle is interposed between the first conductive storage capacitor bottom plate (1101) and the conductive plug (1010), and the second receptacle is interposed between the second conductive storage capacitor bottom plate (1002) and the conductive plug (1010).

With respect to claim 16, Noble (fig. 17) further discloses that the conductive plug (1010) is a first portion of a conductive plug and the semiconductor device further comprises:

a second portion of the conductive plug (1510) electrically connected to the first portion of the conductive plug, wherein the second portion of the conductive plug passes through the opening in the capacitor top plate (1210).

With respect to claim 17, Noble (fig. 17) further discloses that the a dielectric liner (800) having first and second vertical surfaces which contact the conductive plug (1010), wherein the first vertical surface of the dielectric liner is interposed between the first receptacle of the conductive storage capacitor top plate and the conductive plug and the second vertical surface of the dielectric liner is interposed between the second receptacle of the conductive storage capacitor top plate and the conductive plug.

With respect to claim 18, Noble (fig. 17, cols. 6-10) discloses a semiconductor device comprising:

first and second digit line contact plug portions (1010, 1510), wherein the second digit line plug portion (1510) overlies and electrically connects with the first digit line plug portion (1010);

a container capacitor bottom plate (1001) having first and second verticallyoriented, cross-sectional sidewalls and a horizontally-oriented bottom electrically
connected with the first and second sidewalls, wherein the first and second sidewalls
and the bottom define a receptacle and the vertically-oriented sidewalls each having a
first surface inside the receptacle and a second surface outside the receptacle;

a container capacitor top plate (1210) having a first vertically-oriented surface inside the receptacle and second and third vertically-oriented surfaces outside the receptacle, wherein the first and second vertically-oriented surfaces of the top plate are separated from the first vertically-oriented sidewall of the bottom plate by only a capacitor cell dielectric layer (1200) and wherein the second and third surfaces of the top plate, together with a bottom horizontally-oriented surface of the top plate, define a receptacle.

With respect to claim 19, Noble (fig. 17) further discloses that the capacitor top plate (1210) having a hole therein wherein the second digit line plug portion (1510) passes through the hole in the capacitor top plate.

With respect to claim 20, Noble (fig. 17) further discloses that a dielectric liner (800) interposed between the first digit line plug portion (1010) and the receptacle defined by the capacitor top plate (1210).

## Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).
- 6. Claims 6 and 21-22 are rejected under 35 U.S.C. 103(a) as being unpatentable over Noble [U.S. Pat. 6,190,960].

Noble does not teach the height range of the receptacle and the capacitor top plate, as claimed by Applicant. However, the height range would have been obvious to an ordinary artisan practicing the invention because, absent evidence of disclosure of

Application/Control Number: 10/786,348

Art Unit: 2814

criticality for the range giving unexpected results, it is not inventive to discover optimal or workable ranges by routine experimentation. *In re Aller*, 220 F.2d 454, 105 USPQ 233, 235 (CCPA 1955). Furthermore, it appears that these changes produce no functional differences and therefore would have been obvious. See *In re Woodruff*, 919 F.2d 1575, 1578, 16 USPQ2d 1934, 1936 (Fed. Cir. 1990).

#### Conclusion

- 7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Hoai v Pham whose telephone number is 571-272-1715. The examiner can normally be reached on M-F.
- 8. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M Fahmy can be reached on 571-272-1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.
- 9. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

HOAI PHAM PRIMARY EXAMINER Page 8